

# $\mu$ PD44324185B $\mu$ PD44324365B

## 36M-BIT DDR II SRAM SEPARATE I/O 2-WORD BURST OPERATION

R10DS0037EJ0200 Rev.2.00 September 12, 2011

## **Description**

The  $\mu$ PD44324185B is a 2,097,152-word by 18-bit and the  $\mu$ PD44324365B is a 1,048,576-word by 36-bit synchronous double data rate static RAM fabricated with advanced CMOS technology using full CMOS sixtransistor memory cell.

The  $\mu$ PD44324185B and  $\mu$ PD44324365B integrate unique synchronous peripheral circuitry and a burst counter. All input registers controlled by an input clock pair (K and K#) are latched on the positive edge of K and K#. These products are suitable for application which require synchronous operation, high speed, low voltage, high density and wide bit configuration. These products are packaged in 165-pin PLASTIC BGA.

#### **Features**

- $1.8 \pm 0.1$  V power supply
- 165-pin PLASTIC BGA (15 x 17)
- HSTL interface
- PLL circuitry for wide output data valid window and future frequency scaling
- Separate independent read and write data ports
- DDR read or write operation initiated each cycle
- Pipelined double data rate operation
- Separate data input/output bus
- Two-tick burst for low DDR transaction size
- Two input clocks (K and K#) for precise DDR timing at clock rising edges only
- Two output clocks (C and C#) for precise flight time and clock skew matching-clock and data delivered together to receiving device
- Internally self-timed write control
- Clock-stop capability. Normal operation is restored in 20 \(\mu\)s after clock is resumed.
- User programmable impedance output (35 to 70  $\Omega$ )
- Fast clock cycle time: 3.3 ns (300 MHz), 3.5 ns (287 MHz), 4.0 ns (250 MHz), 5.0 ns (200 MHz)
- Simple control logic for easy depth expansion
- JTAG 1149.1 compatible test access port

## **Ordering Information**

Part No.	Organization (word x bit)	Cycle time	Clock frequency	Operating Ambient Temperature	Package
μPD44324185BF5-E33-FQ1-A	2M x 18	3.3ns	300MHz	Ta = 0 to 70°C	165-pin
μPD44324185BF5-E35-FQ1-A		3.5ns	287MHz		PLASTIC BGA
μPD44324185BF5-E40-FQ1-A		4.0ns	250MHz		(15 x 17)
μPD44324185BF5-E50-FQ1-A		5.0ns	200MHz		Lead-free
μPD44324365BF5-E33-FQ1-A	1M x 36	3.3ns	300MHz		
μPD44324365BF5-E35-FQ1-A		3.5ns	287MHz		
μPD44324365BF5-E40-FQ1-A		4.0ns	250MHz		
μPD44324365BF5-E50-FQ1-A		5.0ns	200MHz		
μPD44324185BF5-E33-FQ1	2M x 18	3.3ns	300MHz	Ta = 0 to 70°C	165-pin
μPD44324185BF5-E35-FQ1		3.5ns	287MHz		PLASTIC BGA
μPD44324185BF5-E40-FQ1		4.0ns	250MHz		(15 x 17)
μPD44324185BF5-E50-FQ1		5.0ns	200MHz		Lead
μPD44324365BF5-E33-FQ1	1M x 36	3.3ns	300MHz		
μPD44324365BF5-E35-FQ1		3.5ns	287MHz		
μPD44324365BF5-E40-FQ1		4.0ns	250MHz		
μPD44324365BF5-E50-FQ1		5.0ns	200MHz		
μPD44324185BF5-E33Y-FQ1-A	2M x 18	3.3ns	300MHz	$Ta = -40 \text{ to } 85^{\circ}C$	165-pin
μPD44324185BF5-E35Y-FQ1-A		3.5ns	287MHz		PLASTIC BGA
μPD44324185BF5-E40Y-FQ1-A		4.0ns	250MHz		(15 x 17)
μPD44324185BF5-E50Y-FQ1-A		5.0ns	200MHz		Lead-free
μPD44324365BF5-E33Y-FQ1-A	1M x 36	3.3ns	300MHz		
μPD44324365BF5-E35Y-FQ1-A		3.5ns	287MHz		
μPD44324365BF5-E40Y-FQ1-A		4.0ns	250MHz		
μPD44324365BF5-E50Y-FQ1-A		5.0ns	200MHz		
μPD44324185BF5-E33Y-FQ1	2M x 18	3.3ns	300MHz	$Ta = -40 \text{ to } 85^{\circ}C$	165-pin
μPD44324185BF5-E35Y-FQ1		3.5ns	287MHz		PLASTIC BGA
μPD44324185BF5-E40Y-FQ1		4.0ns	250MHz		(15 x 17)
μPD44324185BF5-E50Y-FQ1		5.0ns	200MHz		Lead
μPD44324365BF5-E33Y-FQ1	1M x 36	3.3ns	300MHz		
μPD44324365BF5-E35Y-FQ1		3.5ns	287MHz		
μPD44324365BF5-E40Y-FQ1		4.0ns	250MHz		
μPD44324365BF5-E50Y-FQ1		5.0ns	200MHz		

#### **Pin Arrangement**

#### 165-pin PLASTIC BGA (15 x 17)

(Top View)

#### [µPD44324185B]

2M x 18

_	1	2	3	4	5	6	7	8	9	10	11
Α	CQ#	Vss/144M	Α	R, W#	BW1#	K#	NC/288M	LD#	Α	Vss/72M	CQ
В	NC	Q9	D9	Α	NC	K	BW0#	Α	NC	NC	Q8
С	NC	NC	D10	Vss	Α	Α	Α	Vss	NC	Q7	D8
D	NC	D11	Q10	Vss	Vss	Vss	Vss	Vss	NC	NC	D7
Ε	NC	NC	Q11	VDDQ	Vss	Vss	Vss	VDDQ	NC	D6	Q6
F	NC	Q12	D12	VDDQ	V <sub>DD</sub>	Vss	V <sub>DD</sub>	VDDQ	NC	NC	Q5
G	NC	D13	Q13	VDDQ	V <sub>DD</sub>	Vss	V <sub>DD</sub>	VDDQ	NC	NC	D5
н	DLL#	VREF	$V_{DD}Q$	VDDQ	V <sub>DD</sub>	Vss	V <sub>DD</sub>	VDDQ	VDDQ	VREF	ZQ
J	NC	NC	D14	VDDQ	V <sub>DD</sub>	Vss	V <sub>DD</sub>	VDDQ	NC	Q4	D4
Κ	NC	NC	Q14	VDDQ	V <sub>DD</sub>	Vss	V <sub>DD</sub>	VDDQ	NC	D3	Q3
L	NC	Q15	D15	VDDQ	Vss	Vss	Vss	VDDQ	NC	NC	Q2
М	NC	NC	D16	Vss	Vss	Vss	Vss	Vss	NC	Q1	D2
N	NC	D17	Q16	Vss	Α	Α	Α	Vss	NC	NC	D1
Р	NC	NC	Q17	Α	Α	С	Α	Α	NC	D0	Q0
R	TDO	тск	Α	Α	Α	C#	Α	Α	Α	TMS	TDI

: Address inputs TMS : IEEE 1149.1 Test input Α D0 to D17 : Data inputs TDI : IEEE 1149.1 Test input Q0 to Q17 TCK : IEEE 1149.1 Clock input : Data outputs LD# : Synchronous load TDO : IEEE 1149.1 Test output : Read Write input : HSTL input reference input R, W#  $V_{REF}$ 

BW0#, BW1# : Byte Write data select  $V_{DD}$ : Power Supply K, K# : Input clock  $V_{DD}Q$ : Power Supply C, C# : Output clock : Ground  $V_{SS}$ CQ, CQ# : Echo clock NC : No connection

ZQ : Output impedance matching NC/xxM : Expansion address for xxMb

DLL# : PLL disable

**Remarks 1.** ×××# indicates active LOW.

2. Refer to Package Dimensions for the index mark.

**3.** 2A, 7A and 10A are expansion addresses : 10A for 72Mb

: 10A and 2A for 144Mb

: 10A, 2A and 7A for 288Mb

2A and 10A of this product can also be used as NC.

#### **Pin Arrangement**

#### 165-pin PLASTIC BGA (15 x 17)

(Top View)

#### [µPD44324365B]

1M x 36

_	1	2	3	4	5	6	7	8	9	10	11
Α	CQ#	Vss/288M	NC/72M	R, W#	BW2#	K#	BW1#	LD#	Α	Vss/144M	CQ
В	Q27	Q18	D18	Α	BW3#	K	BW0#	Α	D17	Q17	Q8
С	D27	Q28	D19	Vss	Α	Α	Α	Vss	D16	Q7	D8
D	D28	D20	Q19	Vss	Vss	Vss	Vss	Vss	Q16	D15	<b>D</b> 7
E	Q29	D29	Q20	VDDQ	Vss	Vss	Vss	VDDQ	Q15	D6	Q6
F	Q30	Q21	D21	VDDQ	V <sub>DD</sub>	Vss	V <sub>DD</sub>	VDDQ	D14	Q14	Q5
G	D30	D22	Q22	VDDQ	V <sub>DD</sub>	Vss	V <sub>DD</sub>	VDDQ	Q13	D13	D5
н	DLL#	VREF	VDDQ	VDDQ	V <sub>DD</sub>	Vss	V <sub>DD</sub>	VDDQ	VDDQ	VREF	ZQ
J	D31	Q31	D23	VDDQ	V <sub>DD</sub>	Vss	V <sub>DD</sub>	VDDQ	D12	Q4	D4
κ	Q32	D32	Q23	V <sub>DD</sub> Q	V <sub>DD</sub>	Vss	V <sub>DD</sub>	VDDQ	Q12	D3	Q3
L	Q33	Q24	D24	$V_{DD}Q$	Vss	Vss	Vss	VDDQ	D11	Q11	Q2
М	D33	Q34	D25	Vss	Vss	Vss	Vss	Vss	D10	Q1	D2
N	D34	D26	Q25	Vss	Α	Α	Α	Vss	Q10	D9	D1
Р	Q35	D35	Q26	Α	Α	С	Α	Α	Q9	D0	Q0
R	TDO	тск	Α	Α	Α	C#	Α	Α	Α	TMS	TDI

A : Address inputs DLL# : PLL disable

D0 to D35 : Data inputs **TMS** : IEEE 1149.1 Test input Q0 to Q35 : Data outputs TDI : IEEE 1149.1 Test input LD# : Synchronous load **TCK** : IEEE 1149.1 Clock input TDO R, W# : Read Write input : IEEE 1149.1 Test output BW0# to BW3# : Byte Write data select  $V_{REF}$ : HSTL input reference input

K, K# : Input clock : Power Supply  $V_{DD}$ C, C# : Output clock  $V_{DD}Q$ : Power Supply CQ, CQ# : Echo clock : Ground  $V_{SS}$ : No connection ZQ : Output impedance matching NC

**Remarks 1.** ×××# indicates active LOW.

2. Refer to Package Dimensions for the index mark.

3. 2A, 3A and 10A are expansion addresses: 3A for 72Mb

: 3A and 10A for 144Mb

: 3A, 10A and 2A for 288Mb

2A and 10A of this product can also be used as NC.

## **Pin Description**

(1/2)

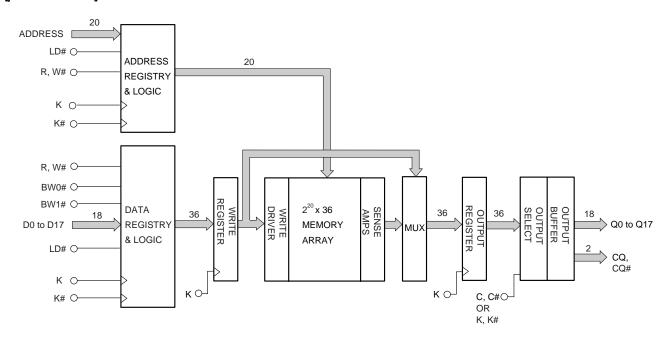
Symbol	Type	Description
А	Input	Synchronous Address Inputs: These inputs are registered and must meet the setup and hold times around the rising edge of K. All transactions operate on a burst of two words (one clock period of bus activity). These inputs are ignored when device is deselected, i.e., NOP (LD# = HIGH).
D0 to Dxx	Input	Synchronous Data Inputs: Input data must meet setup and hold times around the rising edges of K and K# during WRITE operations. See <b>Pin Arrangement</b> for ball site location of individual signals.  x18 device uses D0 to D17.  x36 device uses D0 to D35.
Q0 to Qxx	Output	Synchronous Data Outputs: Output data is synchronized to the respective C and C# or to K and K# rising edges if C and C# are tied HIGH. Data is output in synchronization with C and C# (or K and K#), depending on the LD# and R, W# command. See <b>Pin Arrangement</b> for ball site location of individual signals.  x18 device uses Q0 to Q17.  x36 device uses Q0 to Q35.
LD#	Input	Synchronous Load: This input is brought LOW when a bus cycle sequence is to be defined. This definition includes address and read/write direction. All transactions operate on a burst of 2 data (one clock period of bus activity).
R, W#	Input	Synchronous Read/Write Input: When LD# is LOW, this input designates the access type (READ when R, W# is HIGH, WRITE when R, W# is LOW) for the loaded address. R, W# must meet the setup and hold times around the rising edge of K.
BWx#	Input	Synchronous Byte Writes: When LOW these inputs cause their respective byte to be registered and written during WRITE cycles. These signals must meet setup and hold times around the rising edges of K and K# for each of the two rising edges comprising the WRITE cycle. See Pin Arrangement for signal to data relationships.  x18 device uses BW0#, BW1#.  x36 device uses BW0# to BW3#.  See Byte Write Operation for relation between BWx# and Dxx.
K, K#	Input	Input Clock: This input clock pair registers address and control inputs on the rising edge of K, and registers data on the rising edge of K and the rising edge of K#. K# is ideally 180 degrees out of phase with K. All synchronous inputs must meet setup and hold times around the clock rising edges.
C, C#	Input	Output Clock: This clock pair provides a user controlled means of tuning device output data. The rising edge of C# is used as the output timing reference for first output data. The rising edge of C is used as the output reference for second output data. Ideally, #C is 180 degrees out of phase with C. When use of K and K# as the reference instead of C and C#, then fixed C and C# to HIGH. Operation cannot be guaranteed unless C and C# are fixed to HIGH (i.e. toggle of C and C#)

(2/2)

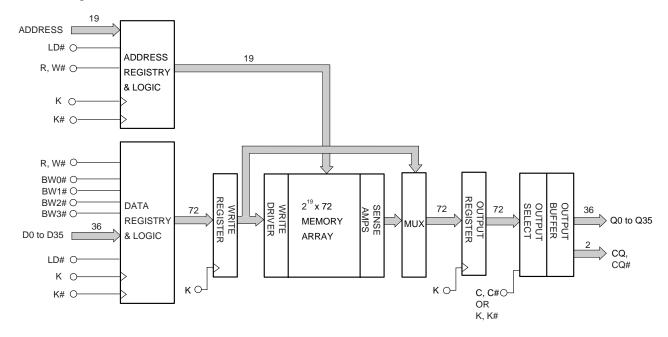
Symbol	Type	Description
CQ, CQ#	Output	Synchronous Echo Clock Outputs. The rising edges of these outputs are tightly matched to the synchronous data outputs and can be used as a data valid indication. These signals run freely and do not stop when Q tristates. If C and C# are stopped (if K and K# are stopped in the single clock mode), CQ and CQ# will also stop.
ZQ	Input	Output Impedance Matching Input: This input is used to tune the device outputs to the system data bus impedance. Q, CQ and CQ# output impedance are set to $0.2 \times RQ$ , where RQ is a resistor from this bump to ground. The output impedance can be minimized by directly connect ZQ to VDDQ. This pin cannot be connected directly to GND or left unconnected. The output impedance is adjusted every 20 $\mu$ s upon power-up to account for drifts in supply voltage and temperature. After replacement for a resistor, the new output impedance is reset by implementing power-on sequence.
DLL#	Input	PLL Disable: When debugging the system or board, the operation can be performed at a clock frequency slower than TKHKH (MAX.) without the PLL circuit being used, if DLL# = LOW. The AC/DC characteristics cannot be guaranteed. For normal operation, DLL# must be HIGH and it can be connected to VDDQ through a 10 k $\Omega$ or less resistor.
TMS TDI	Input	IEEE 1149.1 Test Inputs: 1.8 V I/O level. These balls may be left Not Connected if the JTAG function is not used in the circuit.
TCK	Input	IEEE 1149.1 Clock Input: 1.8 V I/O level. This pin must be tied to VSS if the JTAG function is not used in the circuit.
TDO	Output	IEEE 1149.1 Test Output: 1.8 V I/O level. When providing any external voltage to TDO signal, it is recommended to pull up to VDD.
VREF	_	HSTL Input Reference Voltage: Nominally VDDQ/2. Provides a reference voltage for the input buffers.
VDD	Supply	Power Supply: 1.8 V nominal. See <b>Recommended DC Operating Conditions</b> and <b>DC Characteristics</b> for range.
VDDQ	Supply	Power Supply: Isolated Output Buffer Supply. Nominally 1.5 V. 1.8 V is also permissible. See <b>Recommended DC Operating Conditions</b> and <b>DC Characteristics</b> for range.
VSS	Supply	Power Supply: Ground
NC	_	No Connect: These signals are not connected internally.

## **Block Diagram**

#### [µPD44324185B]



#### [µPD44324365B]



#### Power-On Sequence in DDR II SRAM

DDR II SRAMs must be powered up and initialized in a predefined manner to prevent undefined operations. The following timing charts show the recommended power-on sequence.

The following power-up supply voltage application is recommended:  $V_{SS}$ ,  $V_{DD}$ ,  $V_{DD}Q$ ,  $V_{REF}$ , then  $V_{IN}$ .  $V_{DD}$  and  $V_{DD}Q$  can be applied simultaneously, as long as  $V_{DD}Q$  does not exceed  $V_{DD}$  by more than 0.5 V during power-up. The following power-down supply voltage removal sequence is recommended:  $V_{IN}$ ,  $V_{REF}$ ,  $V_{DD}Q$ ,  $V_{DD}$ ,  $V_{SS}$ .  $V_{DD}$  and  $V_{DD}Q$  can be removed simultaneously, as long as  $V_{DD}Q$  does not exceed  $V_{DD}$  by more than 0.5 V during power-down.

#### **Power-On Sequence**

Apply power and tie DLL# to HIGH.

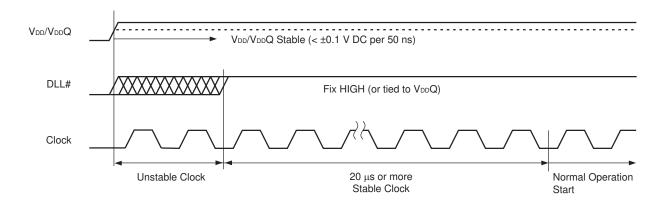
- Apply  $V_{DD}$  before  $V_{DD}Q$ .
- Apply  $V_{\text{DD}}Q$  before  $V_{\text{REF}}$  or at the same time as  $V_{\text{REF}}.$

Provide stable clock for more than 20  $\mu$ s to lock the PLL.

#### **PLL Constraints**

The PLL uses K clock as its synchronizing input and the input should have low phase jitter which is specified as TKC var. The PLL can cover 120 MHz as the lowest frequency. If the input clock is unstable and the PLL is enabled, then the PLL may lock onto an undesired clock frequency.

#### **Power-On Waveforms**



#### **Truth Table**

Operation	LD#	R, W#	CLK	D or Q				
WRITE cycle	L	L	$L\toH$	Data in				
Load address, input write data on				Input data D(A+0)	D(A+1)			
consecutive K and K# rising edge				Input clock K(t+1) ↑ K	#(t+1) ↑			
READ cycle	L	Н	$L\toH$	Data out				
Load address, read data on				Output data Q(A+0)	Q(A+1)			
consecutive C and C# rising edge				Output clock C#(t+1) ↑ C	C(t+2) ↑			
NOP (No operation)	Н	×	$L\toH$	D = x, $Q = High-Z$				
Clock stop	×	×	Stopped	Previous state				

**Remarks 1.** H: HIGH, L: LOW,  $\times$ : don't care,  $\uparrow$ : rising edge.

- 2. Data inputs are registered at K and K# rising edges. Data outputs are delivered at C and C# rising edges except if C and C# are HIGH then Data outputs are delivered at K and K# rising edges.
- **3.** All control inputs in the truth table must meet setup/hold times around the rising edge (LOW to HIGH) of K. All control inputs are registered during the rising edge of K.
- 4. This device contains circuitry that ensure the outputs to be in high impedance during power-up.
- **5.** Refer to state diagram and timing diagrams for clarification.
- **6.** It is recommended that K = K# = C = C# when clock is stopped. This is not essential but permits most rapid restart by overcoming transmission line charging symmetrically.

## **Byte Write Operation**

#### [*µ*PD44324185B]

Operation	K	K#	BW0#	BW1#
Write D0 to D17	$L \rightarrow H$	_	0	0
	ı	$L\toH$	0	0
Write D0 to D8	$L \rightarrow H$	_	0	1
	-	$L \rightarrow H$	0	1
Write D9 to D17	$L\toH$	ı	1	0
	_	$L\toH$	1	0
Write nothing	$L\toH$		1	1
	_	$L\toH$	1	1

**Remarks 1.** H: HIGH, L: LOW,  $\rightarrow$ : rising edge.

2. Assumes a WRITE cycle was initiated. BW0# and BW1# can be altered for any portion of the BURST WRITE operation provided that the setup and hold requirements are satisfied.

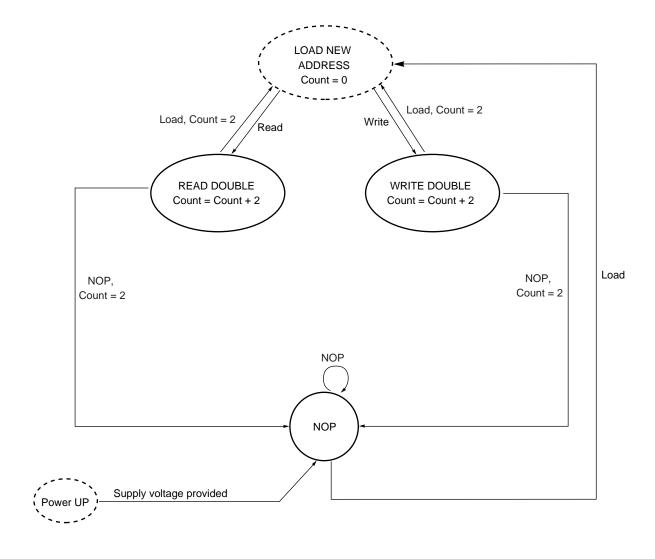
#### [µPD44324365B]

Operation	K	K#	BW0#	BW1#	BW2#	BW3#
Write D0 to D35	$L\toH$	-	0	0	0	0
	-	$L \rightarrow H$	0	0	0	0
Write D0 to D8	$L\toH$	ı	0	1	1	1
	ı	$L\toH$	0	1	1	1
Write D9 to D17	$L\toH$	ı	1	0	1	1
	ı	$L\toH$	1	0	1	1
Write D18 to D26	$L\toH$	ı	1	1	0	1
	ı	$L\toH$	1	1	0	1
Write D27 to D35	$L\toH$	ı	1	1	1	0
	ı	$L\toH$	1	1	1	0
Write nothing	$L\toH$	-	1	1	1	1
	_	$L\toH$	1	1	1	1

**Remarks 1.**  $H: HIGH, L: LOW, \rightarrow : rising edge.$ 

2. Assumes a WRITE cycle was initiated. BW0# to BW3# can be altered for any portion of the BURST WRITE operation provided that the setup and hold requirements are satisfied.

## **Bus Cycle State Diagram**



**Remark** State machine control timing sequence is controlled by K.

#### **Electrical Characteristics**

#### **Absolute Maximum Ratings**

Parameter	Symbol	Conditions	Rating	Unit
Supply voltage	$V_{DD}$		-0.5 to +2.5	V
Output supply voltage	$V_{DD}Q$		−0.5 to V <sub>DD</sub>	V
Input voltage	V <sub>IN</sub>		-0.5 to V <sub>DD</sub> +0.5 (2.5 V MAX.)	٧
Input / Output voltage	V <sub>I/O</sub>		-0.5 to V <sub>DD</sub> Q+0.5 (2.5 V MAX.)	٧
Operating ambient temperature	Та	(E** series)	0 to 70	°C
		(E**Y series)	-40 to 85	
Storage temperature	T <sub>stg</sub>		-55 to +125	°C

Caution Exposing the device to stress above those listed in Absolute Maximum Ratings could cause permanent damage. The device is not meant to be operated under conditions outside the limits described in the operational section of this specification. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

#### Recommended DC Operating Conditions ( $T_A = 0$ to $70^{\circ}$ C, $T_A = -40$ to $85^{\circ}$ C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	Note
Supply voltage	$V_{DD}$		1.7	1.8	1.9	V	
Output supply voltage	$V_{DD}Q$		1.4		$V_{DD}$	٧	1
Input HIGH voltage	V <sub>IH (DC)</sub>		V <sub>REF</sub> +0.1		V <sub>DD</sub> Q+0.3	V	1, 2
Input LOW voltage	V <sub>IL (DC)</sub>		-0.3		V <sub>REF</sub> -0.1	V	1, 2
Clock input voltage	V <sub>IN</sub>		-0.3		V <sub>DD</sub> Q+0.3	V	1, 2
Reference voltage	$V_{REF}$		0.68		0.95	٧	

Notes 1. During normal operation,  $V_{DD}Q$  must not exceed  $V_{DD}$ .

2. Power-up:  $V_{IH} \le V_{DD}Q$  +0.3 V and  $V_{DD} \le 1.7$  V and  $V_{DD}Q \le 1.4$  V for  $t \le 200$  ms

#### Recommended AC Operating Conditions ( $T_A = 0$ to $70^{\circ}$ C, $T_A = -40$ to $85^{\circ}$ C)

Parameter	Symbol	Conditions	MIN.	MAX.	Unit	Note
Input HIGH voltage	V <sub>IH (AC)</sub>		V <sub>REF</sub> +0.2		V	1
Input LOW voltage	V <sub>IL (AC)</sub>			V <sub>REF</sub> -0.2	V	1

**Note 1.** Overshoot:  $V_{IH (AC)} \le V_{DD} + 0.7 \text{ V } (2.5 \text{ V MAX.}) \text{ for } t \le TKHKH/2$ 

Undershoot:  $V_{IL (AC)} \ge -0.5 \text{ V for } t \le TKHKH/2$ 

Control input signals may not have pulse widths less than TKHKL (MIN.) or operate at cycle rates less than

TKHKH (MIN.).

#### DC Characteristics 1 (T<sub>A</sub> = 0 to 70°C, $V_{DD}$ = 1.8 $\pm$ 0.1 V)

Parameter	Symbol	Test condition		MIN.	MA	AX.	Unit	Note
					x18	x36		
Input leakage current	ILI			-2	+	-2	μΑ	
I/O leakage current	ILO			-2	+	-2	μΑ	
Operating supply current	IDD	$VIN \le VIL \text{ or } VIN \ge VIH,$	-E33		530	600	mA	
(Read cycle / Write cycle)		II/O = 0  mA,	-E35		520	580		
		Cycle = MAX.	-E40		480	540		
			-E50		420	470		
Standby supply current	ISB1	$VIN \le VIL \text{ or } VIN \ge VIH,$	-E33		400	420	mA	
(NOP)		II/O = 0 mA,	-E35		390	420		
		Cycle = MAX.	-E40		380	390		
		Inputs static	-E50		350	360		
Output HIGH voltage	VOH(Low)	IOH  ≤ 0.1 mA		V <sub>DD</sub> Q-0.2	V <sub>D</sub>	DQ	V	3, 4
	VOH	Note1		V <sub>DD</sub> Q/2-0.12	V <sub>DD</sub> Q/	2+0.12	V	3, 4
Output LOW voltage	VOL(Low)	IOL ≤ 0.1 mA		V <sub>SS</sub>	0	.2	V	3, 4
	VOL	Note2		V <sub>DD</sub> Q/2-0.12	V <sub>DD</sub> Q/	2+0.12	V	3, 4

**Notes 1.** Outputs are impedance-controlled.  $| \text{IoH} | = (\text{VdDQ/2})/(\text{RQ/5}) \pm 15\%$  for values of 175  $\Omega \le \text{RQ} \le 350 \ \Omega$ .

- 2. Outputs are impedance-controlled. IoL =  $(V_{DD}Q/2)/(RQ/5) \pm 15\%$  for values of 175  $\Omega \le RQ \le 350 \ \Omega$ .
- **3.** AC load current is higher than the shown DC values.
- **4.** HSTL outputs meet JEDEC HSTL Class I standards.

#### DC Characteristics 2 (T<sub>A</sub> = -40 to 85°C, V<sub>DD</sub> = $1.8 \pm 0.1$ V)

Parameter	Symbol	Test condition		MIN.	MAX.		Unit	Note
					x18	x36		
Input leakage current	ILI			-2	+	-2	μΑ	
I/O leakage current	ILO			-2	+	-2	μΑ	
Operating supply current	IDD	$VIN \le VIL \text{ or } VIN \ge VIH,$	-E33Y		680	760	mA	
(Read cycle / Write cycle)		II/O = 0  mA,	-E35Y		670	740		
		Cycle = MAX.	-E40Y		630	690		
			-E50Y		560	620		
Standby supply current	ISB1	$VIN \le VIL \text{ or } VIN \ge VIH,$	-E33Y		530	550	mA	
(NOP)		II/O = 0 mA,	-E35Y		520	540		
		Cycle = MAX.	-E40Y		500	520		
		Inputs static	-E50Y		470	490		
Output HIGH voltage	VOH(Low)	IOH  ≤ 0.1 mA		V <sub>DD</sub> Q-0.2	VD	DQ	V	3, 4
	VOH	Note1		V <sub>DD</sub> Q/2-0.12	V <sub>DD</sub> Q/	2+0.12	V	3, 4
Output LOW voltage	VOL(Low)	IOL ≤ 0.1 mA		V <sub>SS</sub>	0	.2	V	3, 4
	VOL	Note2		V <sub>DD</sub> Q/2-0.12	V <sub>DD</sub> Q/	2+0.12	V	3, 4

**Notes 1.** Outputs are impedance-controlled.  $| \text{IoH} | = (\text{VdDQ/2})/(\text{RQ/5}) \pm 15\%$  for values of 175  $\Omega \le \text{RQ} \le 350 \ \Omega$ .

- 2. Outputs are impedance-controlled. IoL =  $(V_{DD}Q/2)/(RQ/5) \pm 15\%$  for values of 175  $\Omega \le RQ \le 350 \Omega$ .
- **3.** AC load current is higher than the shown DC values.
- **4.** HSTL outputs meet JEDEC HSTL Class I standards.

#### Capacitance ( $T_A = 25^{\circ}C$ , f = 1 MHz)

Parameter	Symbol	Test conditions	MIN.	MAX.	Unit
Input capacitance	C <sub>IN</sub>	$V_{IN} = 0 V$		5	рF
(Address, Control)					
Input / Output capacitance	C <sub>I/O</sub>	$V_{I/O} = 0 V$		7	рF
(DQ, CQ, CQ#)					
Clock Input capacitance	C <sub>clk</sub>	$V_{clk} = 0 V$		6	pF

Remark These parameters are periodically sampled and not 100% tested.

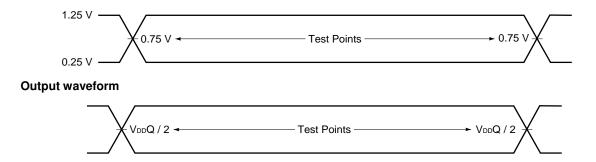
#### **Thermal Characteristics**

Parameter	Symbol	Substrate	Airflow	TYP.	Unit
Thermal resistance	$\theta$ ja	4-layer	0 m/s	21.2	°C/W
from junction to ambient air			1 m/s	13.4	°C/W
		8-layer	0 m/s	20.2	°C/W
			1 m/s	13.0	°C/W
Thermal characterization parameter	$\psi_{ m jt}$	4-layer	0 m/s	0.02	°C/W
from junction to the top center			1 m/s	0.06	°C/W
of the package surface		8-layer	0 m/s	0.02	°C/W
			1 m/s	0.05	°C/W
Thermal resistance	heta jc			2.58	°C/W
from junction to case					

AC Characteristics (Ta = 0 to 70°C or Ta = -40 to 85°C,  $V_{DD}$  = 1.8  $\pm$  0.1 V)

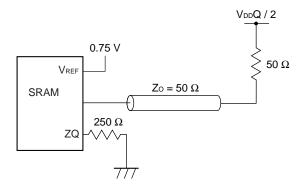
AC Test Conditions (VDD = 1.8  $\pm$  0.1 V, VDDQ = 1.4 V to VDD)

Input waveform (Rise / Fall time ≤ 0.3 ns)



#### **Output load condition**

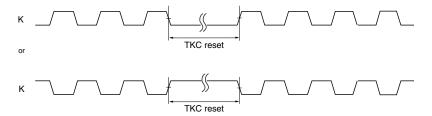
Figure 1. External load at test



## **Read and Write Cycle**

Parameter	Symbol	-		-E35,I		-E40,I		-E50,E		Unit	Note
		(300 I	MHz) MAX.	(287 I MIN.	<u> </u>	(250 I MIN.	MHz) MAX.	(200 Min.	<del> </del>		
Clock		IVITIN.	WAX.	IVIIIV.	WAX.	IVIIIV.	WAX.	IVIIIV.	WAX.		
	TIZLUZU	0.0	0.4	0.5	0.4	4.0	0.4	F 0	0.4		
Average Clock cycle time (K, K#, C, C#)	TKHKH	3.3	8.4	3.5	8.4	4.0	8.4	5.0	8.4	ns	1
Clock phase jitter (K, K#, C, C#)	TKC var		0.2		0.2		0.2		0.2	ns	2
Clock HIGH time (K, K#, C, C#)	TKHKL	1.32		1.5		1.6		2.0		ns	
Clock LOW time (K, K#, C, C#)	TKLKH	1.32		1.5		1.6		2.0		ns	
Clock HIGH to Clock# HIGH (K $\rightarrow$ K#, C $\rightarrow$ C#)	TKHK#H	1.49		1.7		1.8		2.2		ns	
Clock# HIGH to Clock HIGH (K# $\rightarrow$ K, C# $\rightarrow$ C)	TK#HKH	1.49		1.7		1.8		2.2		ns	
Clock to data clock $(K \rightarrow C, K\# \rightarrow C\#)$	TKHCH	0	1.45	0	1.65	0	1.8	0	2.3	ns	
PLL lock time (K, C)	TKC lock	20		20		20		20		uc.	3
K static to PLL reset	TKC lock TKC reset	30		30		30		30		μs ns	4
N Static to FEE 1656t	TRO Teset	30		30		30		30		115	4
Output Times											
CQ HIGH to CQ# HIGH	TCQHCQ#H	1.24		1.35		1.55		1.95		ns	5
$(CQ \rightarrow CQ\#)$											
CQ# HIGH to CQ HIGH	TCQ#HCQH	1.24		1.35		1.55		1.95		ns	5
$(CQ\# \to CQ)$			<u> </u>	<u> </u>					<u> </u>		
C, C# HIGH to output valid	TCHQV		0.45		0.45		0.45		0.45	ns	
C, C# HIGH to output hold	TCHQX	-0.45		-0.45		-0.45		-0.45		ns	
C, C# HIGH to echo clock valid	TCHCQV		0.45		0.45		0.45		0.45	ns	
C, C# HIGH to echo clock hold	TCHCQX	-0.45		-0.45		-0.45		-0.45		ns	
CQ, CQ# HIGH to output valid	TCQHQV		0.27		0.3		0.3		0.35	ns	6
CQ, CQ# HIGH to output hold	TCQHQX	-0.27		-0.3		-0.3		-0.35		ns	6
C HIGH to output High-Z	TCHQZ		0.45		0.45		0.45		0.45	ns	
C HIGH to output Low-Z	TCHQX1	-0.45		-0.45		-0.45		-0.45		ns	
Setup Times	1										
Address valid to K rising edge	TAVKH	0.4		0.5		0.5		0.6		ns	7
Synchronous load input (LD#), read write input (R, W#) valid to	TIVKH	0.4		0.5		0.5		0.6		ns	7
K rising edge											
Data inputs and write data	TDVKH	0.3		0.35		0.35		0.4		ns	7
select inputs (BWx#) valid to											
K, K# rising edge											
Hold Times	1										
Hold Times	TIZILANZ	0.4	1	0.5	l	0.5	l	0.0	1		l -
K rising edge to address hold	TKHAX	0.4		0.5		0.5		0.6		ns	7
K rising edge to synchronous load input (LD#), read write input (R, W#) hold	TKHIX	0.4		0.5		0.5		0.6		ns	7
K, K# rising edge to data inputs and write data select inputs (BWx#) hold	TKHDX	0.3		0.35		0.35		0.4		ns	7

- **Notes 1.** When debugging the system or board, these products can operate at a clock frequency slower than TKHKH (MAX.) without the PLL circuit being used, if DLL# = LOW. Read latency (RL) is changed to 1.0 clock cycle in this operation. The AC/DC characteristics cannot be guaranteed, however.
  - 2. Clock phase jitter is the variance from clock rising edge to the next expected clock rising edge. TKC var (MAX.) indicates a peak-to-peak value.
  - 3.  $V_{DD}$  slew rate must be less than 0.1 V DC per 50 ns for PLL lock retention. PLL lock time begins once  $V_{DD}$  and input clock are stable. It is recommended that the device is kept NOP (LD# = HIGH) during these cycles.
  - **4.** K input is monitored for this operation. See below for the timing.

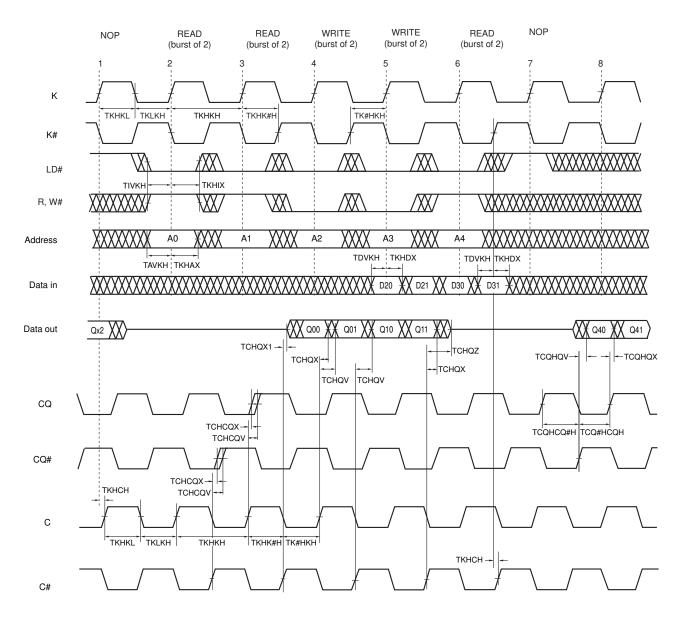


- 5. Guaranteed by design.
- **6.** Echo clock is very tightly controlled to data valid / data hold. By design, there is a  $\pm$  0.1 ns variation from echo clock to data. The data sheet parameters reflect tester guardbands and test setup variations.
- 7. This is a synchronous device. All addresses, data and control lines must meet the specified setup and hold times for all latching clock edges.

#### **Remarks 1.** This parameter is sampled.

- Test conditions as specified with the output loading as shown in AC Test Conditions unless otherwise noted.
- 3. Control input signals may not be operated with pulse widths less than TKHKL (MIN.).
- **4.** If C, C# are tied HIGH, K, K# become the references for C, C# timing parameters.
- **5.**  $V_{DD}Q$  is 1.5 V DC.

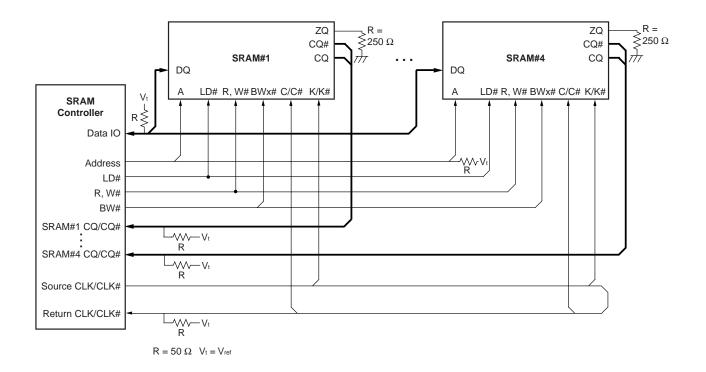
### **Read and Write Timing**



**Remarks 1.** Q01 refers to output from address A0+0. Q02 refers to output from the next internal burst address following A0, i.e., A0+1.

- 2. Outputs are disabled (high impedance) 2.5 clock cycles after the last READ (LD# = LOW, R, W# = HIGH) is input in the sequences of [READ]-[NOP] and [READ]-[WRITE].
- 3. In this example, if address A4 = A3, data Q41 = D31 and Q42 = D32. Write data is forwarded immediately as read results.

#### **Application Example**



Remark AC Characteristics are defined at the condition of SRAM outputs, CQ, CQ# and DQ with termination.

## **JTAG Specification**

These products support a limited set of JTAG functions as in IEEE standard 1149.1.

**Test Access Port (TAP) Pins** 

Pin name	Pin assignments	Description
TCK	2R	Test Clock Input. All input are captured on the rising edge of TCK and all outputs propagate from the falling edge of TCK.
TMS	10R	Test Mode Select. This is the command input for the TAP controller state machine.
TDI	11R	Test Data Input. This is the input side of the serial registers placed between TDI and TDO. The register placed between TDI and TDO is determined by the state of the TAP controller state machine and the instruction that is currently loaded in the TAP instruction.
TDO	1R	Test Data Output. This is the output side of the serial registers placed between TDI and TDO. Output changes in response to the falling edge of TCK.

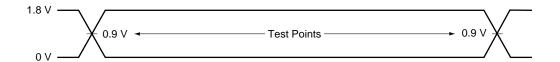
**Remark** The device does not have TRST (TAP reset). The Test-Logic Reset state is entered while TMS is held HIGH for five rising edges of TCK. The TAP controller state is also reset on the SRAM POWER-UP.

JTAG DC Characteristics (TA = 0 to 70°C,  $V_{DD}$  = 1.8  $\pm$  0.1 V, unless otherwise noted)

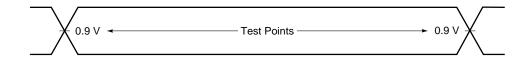
Parameter	Symbol	Conditions	MIN.	MAX.	Unit
JTAG Input leakage current	ILI	$0 \text{ V} \leq V_{IN} \leq V_{DD}$	-5.0	+5.0	μΑ
JTAG I/O leakage current	I <sub>LO</sub>	$0\ V \leq V_{IN} \leq V_{DD}Q,$	-5.0	+5.0	μΑ
		Outputs disabled			
JTAG input HIGH voltage	$V_{IH}$		1.3	V <sub>DD</sub> +0.3	V
JTAG input LOW voltage	$V_{IL}$		-0.3	+0.5	V
JTAG output HIGH voltage	$V_{\text{OH1}}$	I <sub>OHC</sub>   = 100 μA	1.6		V
	$V_{\text{OH2}}$	I <sub>OHT</sub>   = 2 mA	1.4		V
JTAG output LOW voltage	$V_{OL1}$	$I_{OLC} = 100 \mu A$		0.2	V
	$V_{OL2}$	I <sub>OLT</sub> = 2 mA		0.4	V

#### **JTAG AC Test Conditions**

#### Input waveform (Rise / Fall time ≤ 1 ns)

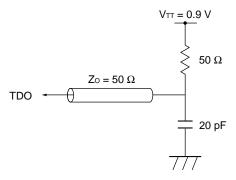


## Output waveform



#### **Output load**

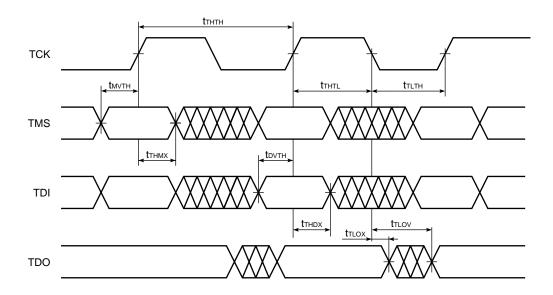
Figure 2. External load at test



JTAG AC Characteristics (T<sub>A</sub> = 0 to 70°C)

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
Clock					
Clock cycle time	tтнтн		50		ns
Clock frequency	f <sub>TF</sub>			20	MHz
Clock HIGH time	t <sub>THTL</sub>		20		ns
Clock LOW time	t <sub>TLTH</sub>		20		ns
Output time					
TCK LOW to TDO unknown	t <sub>TLOX</sub>		0		ns
TCK LOW to TDO valid	t <sub>TLOV</sub>			10	ns
Setup time					
TMS setup time	t <sub>MVTH</sub>		5		ns
TDI valid to TCK HIGH	t <sub>DVTH</sub>		5		ns
Capture setup time	t <sub>CS</sub>		5		ns
Hold time					
TMS hold time	t <sub>THMX</sub>		5		ns
TCK HIGH to TDI invalid	t <sub>THDX</sub>		5		ns
Capture hold time	t <sub>CH</sub>		5		ns

## JTAG Timing Diagram



## Scan Register Definition (1)

Register name	Description
Instruction register	The instruction register holds the instructions that are executed by the TAP controller when it is moved into the run-test/idle or the various data register state. The register can be loaded when it is placed between the TDI and TDO pins. The instruction register is automatically preloaded with the IDCODE instruction at power-up whenever the controller is placed in test-logic-reset state.
Bypass register	The bypass register is a single bit register that can be placed between TDI and TDO. It allows serial test data to be passed through the RAMs TAP to another device in the scan chain with as little delay as possible.
ID register	The ID Register is a 32 bit register that is loaded with a device and vendor specific 32 bit code when the controller is put in capture-DR state with the IDCODE command loaded in the instruction register. The register is then placed between the TDI and TDO pins when the controller is moved into shift-DR state.
Boundary register	The boundary register, under the control of the TAP controller, is loaded with the contents of the RAMs I/O ring when the controller is in capture-DR state and then is placed between the TDI and TDO pins when the controller is moved to shift-DR state. Several TAP instructions can be used to activate the boundary register.  The Scan Exit Order tables describe which device bump connects to each boundary register location. The first column defines the bit's position in the boundary register. The second column is the name of the input or I/O at the bump and the third column is the bump number.

## Scan Register Definition (2)

Register name	Bit size	Unit
Instruction register	3	bit
Bypass register	1	bit
ID register	32	bit
Boundary register	109	bit

## **ID Register Definition**

Part number	Organization	ID [31:28] vendor revision no.	ID [27:12] part no.	ID [11:1] vendor ID no.	ID [0] fix bit
μPD44324185B	2M x 18	XXXX	0000 0000 0100 0111	00000010000	1
μPD44324365B	1M x 36	XXXX	0000 0000 0100 1000	00000010000	1

#### **SCAN Exit Order**

Bit	Signal	Bump	
no.	x18		
1	C		ID 6R
2			6P
3	-		6N
4	-		7P
5	-		7N
6	,		7R
7	,		8R
8	,		8P
9			9R
10	Q		11P
11	D		10P
12	NC	D9	10N
13	NC	Q9	9P
14	Q		10M
15	D		11N
16	NC	D10	9M
17	NC	Q10	9N
18	Q		11L
19	D		11M
20	NC	D11	9L
21	NC	Q11	10L
22	Q	<u> </u>	11K
23	D		10K
24	NC	D12	9J
25	NC	Q12	9K
26	Q		10J
27	D		11J
28	Z		11H
29	NC	D13	10G
30	NC	Q13	9G
31	Q5		11F
32	D5		11G
33	NC	D14	9F
34	NC	Q14	10F
35	Q	11E	
36	D		10E

Bit	Signal	name	Bump
no.	x18	x36	ID
37	NC	D15	10D
38	NC	Q15	9E
39	C	7	10C
40	С	7	11D
41	NC	D16	9C
42	NC	Q16	9D
43	C	18	11B
44	D	8	11C
45	NC	D17	9B
46	NC	Q17	10B
47	С	Q	11A
48	VS	SS	10A
49	,	4	9A
50	,	4	8B
51	,	Ą	7C
52	,	4	6C
53	L[	D#	8A
54	NC	BW1#	7A
55	BW0#	BW0#	7B
56	ŀ	<	6B
57	K	#	6A
58	NC	BW3#	5B
59	BW1#	BW2#	5A
60	R,	W#	4A
61	,	4	5C
62	,	Ą	4B
63	Α	NC	3A
64	VS	SS	2A
65	C	Q#	1A
66	Q9	Q18	2B
67	D9	D18	3B
68	NC	D27	1C
69	NC	Q27	1B
70	Q10	Q19	3D
71	D10	D19	3C
72	NC	D28	1D

Bit no.         Signal → ame no.         Bump no.           73         NC         Q28         2C           74         Q11         Q20         3E           75         D11         D20         2D           76         NC         D29         2E           77         NC         Q29         1E           78         Q12         Q21         2F           79         D12         D21         3F           80         NC         D30         1G           81         NC         Q30         1F           82         Q13         Q22         3G           83         D13         D22         2G           84         DL#         1H           85         NC         D31         1J           86         NC         Q31         2J           87         Q14         Q23         3K           88         D14         D23         3J           89         NC         D32         2K           90         NC         Q32         1K           91         Q15         Q24         2L           92         D15				
73         NC         Q28         2C           74         Q11         Q20         3E           75         D11         D20         2D           76         NC         D29         2E           77         NC         Q29         1E           78         Q12         Q21         2F           79         D12         D21         3F           80         NC         D30         1G           81         NC         Q30         1F           82         Q13         Q22         3G           83         D13         D22         2G           84         DL#         1H           85         NC         D31         1J           86         NC         Q31         2J           87         Q14         Q23         3K           88         D14         D23         3J           89         NC         D32         2K           90         NC         Q32         1K           91         Q15         Q24         2L           92         D15         D24         3L           95         Q16	Bit	Signal name		Bump
74         Q11         Q20         3E           75         D11         D20         2D           76         NC         D29         2E           77         NC         Q29         1E           78         Q12         Q21         2F           79         D12         D21         3F           80         NC         D30         1G           81         NC         Q30         1F           82         Q13         Q22         3G           83         D13         D22         2G           84         DL#         1H           85         NC         D31         1J           86         NC         Q31         2J           87         Q14         Q23         3K           88         D14         D23         3J           89         NC         D32         2K           90         NC         Q32         1K           91         Q15         Q24         2L           92         D15         D24         3L           93         NC         D33         1M           94         NC	no.	x18 x36		ID
75         D11         D20         2D           76         NC         D29         2E           77         NC         Q29         1E           78         Q12         Q21         2F           79         D12         D21         3F           80         NC         D30         1G           81         NC         Q30         1F           82         Q13         Q22         3G           83         D13         D22         2G           84         DL#         1H           85         NC         D31         1J           86         NC         Q31         2J           87         Q14         Q23         3K           88         D14         D23         3J           89         NC         D32         2K           90         NC         Q32         1K           91         Q15         Q24         2L           92         D15         D24         3L           93         NC         D33         1M           94         NC         Q33         1L           95         Q16	73	NC Q28		2C
76         NC         D29         2E           77         NC         Q29         1E           78         Q12         Q21         2F           79         D12         D21         3F           80         NC         D30         1G           81         NC         Q30         1F           82         Q13         Q22         3G           83         D13         D22         2G           84         DL#         1H         1H           85         NC         D31         1J           86         NC         Q31         2J           87         Q14         Q23         3K           88         D14         D23         3J           89         NC         D32         2K           90         NC         Q32         1K           91         Q15         Q24         2L           92         D15         D24         3L           93         NC         D33         1M           94         NC         Q33         1L           95         Q16         Q25         3N           96	74	Q11	Q20	3E
77         NC         Q29         1E           78         Q12         Q21         2F           79         D12         D21         3F           80         NC         D30         1G           81         NC         Q30         1F           82         Q13         Q22         3G           83         D13         D22         2G           84         DLL#         1H           85         NC         D31         1J           86         NC         Q31         2J           87         Q14         Q23         3K           88         D14         D23         3J           89         NC         D32         2K           90         NC         Q32         1K           91         Q15         Q24         2L           92         D15         D24         3L           93         NC         D33         1M           94         NC         Q33         1L           95         Q16         Q25         3N           96         D16         D25         3M           97         NC	75	D11	D20	2D
78         Q12         Q21         2F           79         D12         D21         3F           80         NC         D30         1G           81         NC         Q30         1F           82         Q13         Q22         3G           83         D13         D22         2G           84         DLL#         1H           85         NC         D31         1J           86         NC         Q31         2J           87         Q14         Q23         3K           88         D14         D23         3J           89         NC         D32         2K           90         NC         Q32         1K           91         Q15         Q24         2L           92         D15         D24         3L           93         NC         D33         1M           94         NC         Q33         1L           95         Q16         Q25         3N           96         D16         D25         3M           97         NC         D34         1N           98         NC	76	NC	D29	2E
79         D12         D21         3F           80         NC         D30         1G           81         NC         Q30         1F           82         Q13         Q22         3G           83         D13         D22         2G           84         DL#         1H           85         NC         D31         1J           86         NC         Q31         2J           87         Q14         Q23         3K           88         D14         D23         3J           89         NC         D32         2K           90         NC         Q32         1K           91         Q15         Q24         2L           92         D15         D24         3L           93         NC         D33         1M           94         NC         Q33         1L           95         Q16         Q25         3N           96         D16         D25         3M           97         NC         D34         1N           98         NC         Q34         2M           99         Q17	77	NC	Q29	1E
80         NC         D30         1G           81         NC         Q30         1F           82         Q13         Q22         3G           83         D13         D22         2G           84         DLL#         1H           85         NC         D31         1J           86         NC         Q31         2J           87         Q14         Q23         3K           88         D14         D23         3J           89         NC         D32         2K           90         NC         Q32         1K           91         Q15         Q24         2L           92         D15         D24         3L           93         NC         D33         1M           94         NC         Q33         1L           95         Q16         Q25         3N           96         D16         D25         3M           97         NC         D34         1N           98         NC         Q34         2M           99         Q17         Q26         3P           100         D17	78	Q12	Q21	2F
81       NC       Q30       1F         82       Q13       Q22       3G         83       D13       D22       2G         84       DL#       1H         85       NC       D31       1J         86       NC       Q31       2J         87       Q14       Q23       3K         88       D14       D23       3J         89       NC       D32       2K         90       NC       Q32       1K         91       Q15       Q24       2L         92       D15       D24       3L         93       NC       D33       1M         94       NC       Q33       1L         95       Q16       Q25       3N         96       D16       D25       3M         97       NC       D34       1N         98       NC       Q34       2M         99       Q17       Q26       3P         100       D17       D26       2N         101       NC       D35       2P         102       NC       Q35       1P	79	D12	D21	3F
82       Q13       Q22       3G         83       D13       D22       2G         84       DL#       1H         85       NC       D31       1J         86       NC       Q31       2J         87       Q14       Q23       3K         88       D14       D23       3J         89       NC       D32       2K         90       NC       Q32       1K         91       Q15       Q24       2L         92       D15       D24       3L         93       NC       D33       1M         94       NC       Q33       1L         95       Q16       Q25       3N         96       D16       D25       3M         97       NC       D34       1N         98       NC       Q34       2M         99       Q17       Q26       3P         100       D17       D26       2N         101       NC       D35       2P         102       NC       Q35       1P         103       A       3R         104	80	NC	D30	1G
83         D13         D22         2G           84         DLL#         1H           85         NC         D31         1J           86         NC         Q31         2J           87         Q14         Q23         3K           88         D14         D23         3J           89         NC         D32         2K           90         NC         Q32         1K           91         Q15         Q24         2L           92         D15         D24         3L           93         NC         D33         1M           94         NC         Q33         1L           95         Q16         Q25         3N           96         D16         D25         3M           97         NC         D34         1N           98         NC         Q34         2M           99         Q17         Q26         3P           100         D17         D26         2N           101         NC         D35         2P           102         NC         Q35         1P           103         A	81	NC	Q30	1F
84         DL#         1H           85         NC         D31         1J           86         NC         Q31         2J           87         Q14         Q23         3K           88         D14         D23         3J           89         NC         D32         2K           90         NC         Q32         1K           91         Q15         Q24         2L           92         D15         D24         3L           93         NC         D33         1M           94         NC         Q33         1L           95         Q16         Q25         3N           96         D16         D25         3M           97         NC         D34         1N           98         NC         Q34         2M           99         Q17         Q26         3P           100         D17         D26         2N           101         NC         D35         2P           102         NC         Q35         1P           103         A         3R           104         A         4R     <	82	Q13	Q22	3G
85         NC         D31         1J           86         NC         Q31         2J           87         Q14         Q23         3K           88         D14         D23         3J           89         NC         D32         2K           90         NC         Q32         1K           91         Q15         Q24         2L           92         D15         D24         3L           93         NC         D33         1M           94         NC         Q33         1L           95         Q16         Q25         3N           96         D16         D25         3M           97         NC         D34         1N           98         NC         Q34         2M           99         Q17         Q26         3P           100         D17         D26         2N           101         NC         D35         2P           102         NC         Q35         1P           103         A         3R           104         A         4R           105         A         4P </td <td>83</td> <td>D13</td> <td>D22</td> <td>2G</td>	83	D13	D22	2G
86         NC         Q31         2J           87         Q14         Q23         3K           88         D14         D23         3J           89         NC         D32         2K           90         NC         Q32         1K           91         Q15         Q24         2L           92         D15         D24         3L           93         NC         D33         1M           94         NC         Q33         1L           95         Q16         Q25         3N           96         D16         D25         3M           97         NC         D34         1N           98         NC         Q34         2M           99         Q17         Q26         3P           100         D17         D26         2N           101         NC         D35         2P           102         NC         Q35         1P           103         A         3R           104         A         4R           105         A         4P           106         A         5P	84	DL	L#	1H
87         Q14         Q23         3K           88         D14         D23         3J           89         NC         D32         2K           90         NC         Q32         1K           91         Q15         Q24         2L           92         D15         D24         3L           93         NC         D33         1M           94         NC         Q33         1L           95         Q16         Q25         3N           96         D16         D25         3M           97         NC         D34         1N           98         NC         Q34         2M           99         Q17         Q26         3P           100         D17         D26         2N           101         NC         D35         2P           102         NC         Q35         1P           103         A         3R           104         A         4R           105         A         4P           106         A         5P           107         A         5N           108	85	NC	D31	1J
88         D14         D23         3J           89         NC         D32         2K           90         NC         Q32         1K           91         Q15         Q24         2L           92         D15         D24         3L           93         NC         D33         1M           94         NC         Q33         1L           95         Q16         Q25         3N           96         D16         D25         3M           97         NC         D34         1N           98         NC         Q34         2M           99         Q17         Q26         3P           100         D17         D26         2N           101         NC         D35         2P           102         NC         Q35         1P           103         A         3R           104         A         4R           105         A         4P           106         A         5P           107         A         5N           108         A         5R	86	NC	Q31	2J
89         NC         D32         2K           90         NC         Q32         1K           91         Q15         Q24         2L           92         D15         D24         3L           93         NC         D33         1M           94         NC         Q33         1L           95         Q16         Q25         3N           96         D16         D25         3M           97         NC         D34         1N           98         NC         Q34         2M           99         Q17         Q26         3P           100         D17         D26         2N           101         NC         D35         2P           102         NC         Q35         1P           103         A         3R           104         A         4R           105         A         4P           106         A         5P           107         A         5N           108         A         5R	87	Q14	Q23	ЗК
90         NC         Q32         1K           91         Q15         Q24         2L           92         D15         D24         3L           93         NC         D33         1M           94         NC         Q33         1L           95         Q16         Q25         3N           96         D16         D25         3M           97         NC         D34         1N           98         NC         Q34         2M           99         Q17         Q26         3P           100         D17         D26         2N           101         NC         D35         2P           102         NC         Q35         1P           103         A         3R           104         A         4R           105         A         4P           106         A         5P           107         A         5N           108         A         5R	88	D14	D23	3J
91         Q15         Q24         2L           92         D15         D24         3L           93         NC         D33         1M           94         NC         Q33         1L           95         Q16         Q25         3N           96         D16         D25         3M           97         NC         D34         1N           98         NC         Q34         2M           99         Q17         Q26         3P           100         D17         D26         2N           101         NC         D35         2P           102         NC         Q35         1P           103         A         3R           104         A         4R           105         A         4P           106         A         5P           107         A         5N           108         A         5R	89	NC	D32	2K
92         D15         D24         3L           93         NC         D33         1M           94         NC         Q33         1L           95         Q16         Q25         3N           96         D16         D25         3M           97         NC         D34         1N           98         NC         Q34         2M           99         Q17         Q26         3P           100         D17         D26         2N           101         NC         D35         2P           102         NC         Q35         1P           103         A         3R           104         A         4R           105         A         4P           106         A         5P           107         A         5N           108         A         5R	90	NC	Q32	1K
93         NC         D33         1M           94         NC         Q33         1L           95         Q16         Q25         3N           96         D16         D25         3M           97         NC         D34         1N           98         NC         Q34         2M           99         Q17         Q26         3P           100         D17         D26         2N           101         NC         D35         2P           102         NC         Q35         1P           103         A         3R           104         A         4R           105         A         4P           106         A         5P           107         A         5N           108         A         5R	91	Q15 Q24		2L
94         NC         Q33         1L           95         Q16         Q25         3N           96         D16         D25         3M           97         NC         D34         1N           98         NC         Q34         2M           99         Q17         Q26         3P           100         D17         D26         2N           101         NC         D35         2P           102         NC         Q35         1P           103         A         3R           104         A         4R           105         A         4P           106         A         5P           107         A         5N           108         A         5R	92	D15 D24		3L
95         Q16         Q25         3N           96         D16         D25         3M           97         NC         D34         1N           98         NC         Q34         2M           99         Q17         Q26         3P           100         D17         D26         2N           101         NC         D35         2P           102         NC         Q35         1P           103         A         3R           104         A         4R           105         A         4P           106         A         5P           107         A         5N           108         A         5R	93	NC D33		1M
96         D16         D25         3M           97         NC         D34         1N           98         NC         Q34         2M           99         Q17         Q26         3P           100         D17         D26         2N           101         NC         D35         2P           102         NC         Q35         1P           103         A         3R           104         A         4R           105         A         4P           106         A         5P           107         A         5N           108         A         5R	94	NC	Q33	1L
97         NC         D34         1N           98         NC         Q34         2M           99         Q17         Q26         3P           100         D17         D26         2N           101         NC         D35         2P           102         NC         Q35         1P           103         A         3R           104         A         4R           105         A         4P           106         A         5P           107         A         5N           108         A         5R	95	Q16	Q25	3N
98         NC         Q34         2M           99         Q17         Q26         3P           100         D17         D26         2N           101         NC         D35         2P           102         NC         Q35         1P           103         A         3R           104         A         4R           105         A         4P           106         A         5P           107         A         5N           108         A         5R	96	D16	D25	ЗМ
99         Q17         Q26         3P           100         D17         D26         2N           101         NC         D35         2P           102         NC         Q35         1P           103         A         3R           104         A         4R           105         A         4P           106         A         5P           107         A         5N           108         A         5R	97	NC	D34	1N
100         D17         D26         2N           101         NC         D35         2P           102         NC         Q35         1P           103         A         3R           104         A         4R           105         A         4P           106         A         5P           107         A         5N           108         A         5R	98	NC	Q34	2M
101         NC         D35         2P           102         NC         Q35         1P           103         A         3R           104         A         4R           105         A         4P           106         A         5P           107         A         5N           108         A         5R	99	Q17	Q26	3P
102         NC         Q35         1P           103         A         3R           104         A         4R           105         A         4P           106         A         5P           107         A         5N           108         A         5R	100	D17	D26	2N
103       A       3R         104       A       4R         105       A       4P         106       A       5P         107       A       5N         108       A       5R	101	NC	D35	2P
104       A       4R         105       A       4P         106       A       5P         107       A       5N         108       A       5R	102			1P
105     A     4P       106     A     5P       107     A     5N       108     A     5R	103	A		3R
106     A     5P       107     A     5N       108     A     5R	104	A		4R
107 A 5N 108 A 5R	105	Α		4P
108 A 5R	106	Α		5P
	107	А		5N
109 – Internal	108	A		5R
	109	_		Internal

**Remark** Bump ID 10A of bit no. 48 and Bump ID 2A of bit no. 64 can also be used as NC.

The register always indicates LOW, however.

#### **JTAG Instructions**

Instructions	Description
EXTEST	The EXTEST instruction allows circuitry external to the component package to be tested. Boundary-scan register cells at output pins are used to apply test vectors, while those at input pins capture test results. Typically, the first test vector to be applied using the EXTEST instruction will be shifted into the boundary scan register using the PRELOAD instruction. Thus, during the update-IR state of EXTEST, the output drive is turned on and the PRELOAD data is driven onto the output pins.
IDCODE	The IDCODE instruction causes the ID ROM to be loaded into the ID register when the controller is in capture-DR mode and places the ID register between the TDI and TDO pins in shift-DR mode. The IDCODE instruction is the default instruction loaded in at power up and any time the controller is placed in the test-logic-reset state.
BYPASS	When the BYPASS instruction is loaded in the instruction register, the bypass register is placed between TDI and TDO. This occurs when the TAP controller is moved to the shift-DR state. This allows the board level scan path to be shortened to facilitate testing of other devices in the scan path.
SAMPLE / PRELOAD	SAMPLE / PRELOAD is a Standard 1149.1 mandatory public instruction. When the SAMPLE / PRELOAD instruction is loaded in the instruction register, moving the TAP controller into the capture-DR state loads the data in the RAMs input and DQ pins into the boundary scan register. Because the RAM clock(s) are independent from the TAP clock (TCK) it is possible for the TAP to attempt to capture the I/O ring contents while the input buffers are in transition (i.e., in a metastable state). Although allowing the TAP to sample metastable input will not harm the device, repeatable results cannot be expected. RAM input signals must be stabilized for long enough to meet the TAPs input data capture setup plus hold time (tCS plus tCH). The RAMs clock inputs need not be paused for any other TAP operation except capturing the I/O ring contents into the boundary scan register. Moving the controller to shift-DR state then places the boundary scan register between the TDI and TDO pins.
SAMPLE-Z	If the SAMPLE-Z instruction is loaded in the instruction register, all RAM DQ pins are forced to an inactive drive state (high impedance) and the boundary register is connected between TDI and TDO when the TAP controller is moved to the shift-DR state.

#### **JTAG Instruction Coding**

IR2	IR1	IR0	Instruction	Note
0	0	0	EXTEST	
0	0	1	IDCODE	
0	1	0	SAMPLE-Z	1
0	1	1	RESERVED	2
1	0	0	SAMPLE / PRELOAD	
1	0	1	RESERVED	2
1	1	0	RESERVED	2
1	1	1	BYPASS	

**Notes 1.** TRISTATE all DQ pins and CAPTURE the pad values into a SERIAL SCAN LATCH.

2. Do not use this instruction code because the vendor uses it to evaluate this product.

#### Output Pin States of CQ, CQ# and Q

Instructions	Control-Register Status	Output Pin Status	
		CQ,CQ#	Q
EXTEST	0	Update	High-Z
	1	Update	Update
IDCODE	0	SRAM	SRAM
	1	SRAM	SRAM
SAMPLE-Z	0	High-Z	High-Z
	1	High-Z	High-Z
SAMPLE	0	SRAM	SRAM
	1	SRAM	SRAM
BYPASS	0	SRAM	SRAM
	1	SRAM	SRAM

**Remark** The output pin statuses during each instruction vary according to the Control-Register status (value of Boundary Scan Register, bit no. 109).

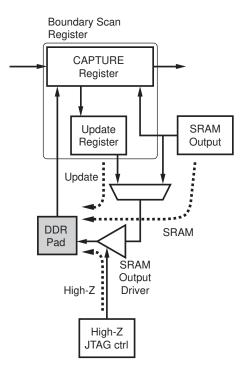
There are three statuses:

Update: Contents of the "Update Register" are output to the output pin (DDR Pad).

SRAM : Contents of the SRAM internal output "SRAM Output" are output to the output pin (DDR Pad).

High-Z :The output pin (DDR Pad) becomes high impedance by controlling of the "High-Z JTAG ctrl".

The Control-Register status is set during Update-DR at the EXTEST or SAMPLE instruction.



#### Boundary Scan Register Status of Output Pins CQ, CQ# and Q

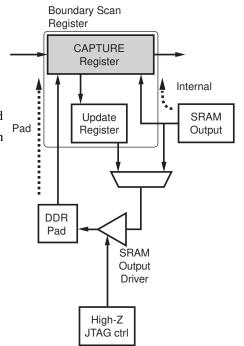
Instructions	SRAM Status	Boundary Scan Register Status		Note
		CQ,CQ#	Q	
EXTEST	READ (Low-Z)	Pad	Pad	
	NOP (High-Z)	Pad	Pad	
IDCODE	READ (Low-Z)	_	_	No definition
	NOP (High-Z)	_	_	
SAMPLE-Z	READ (Low-Z)	Pad	Pad	
	NOP (High-Z)	Pad	Pad	
SAMPLE	READ (Low-Z)	Internal	Internal	
	NOP (High-Z)	Internal	Pad	
BYPASS	READ (Low-Z)	_	_	No definition
	NOP (High-Z)	_	_	

**Remark** The Boundary Scan Register statuses during execution each instruction vary according to the instruction code and SRAM operation mode.

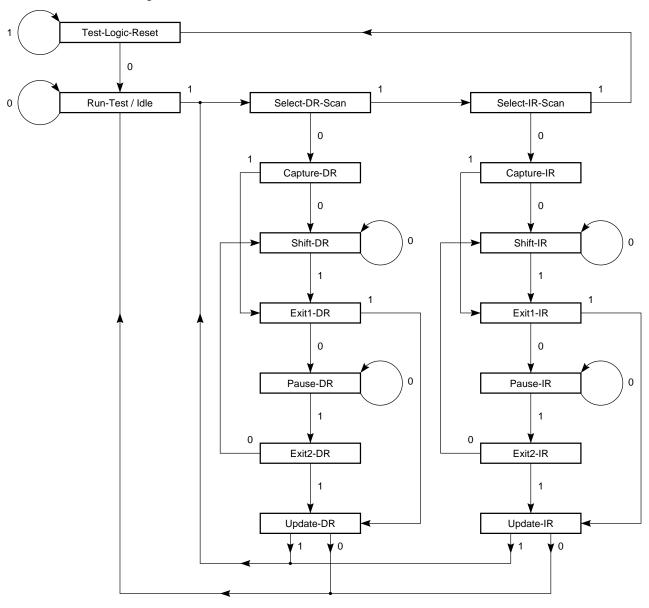
There are two statuses:

Pad : Contents of the output pin (DDR Pad) are captured in the "CAPTURE Register" in the Boundary Scan Register.

Internal: Contents of the SRAM internal output "SRAM Output" are captured in the "CAPTURE Register" in the Boundary Scan Register.

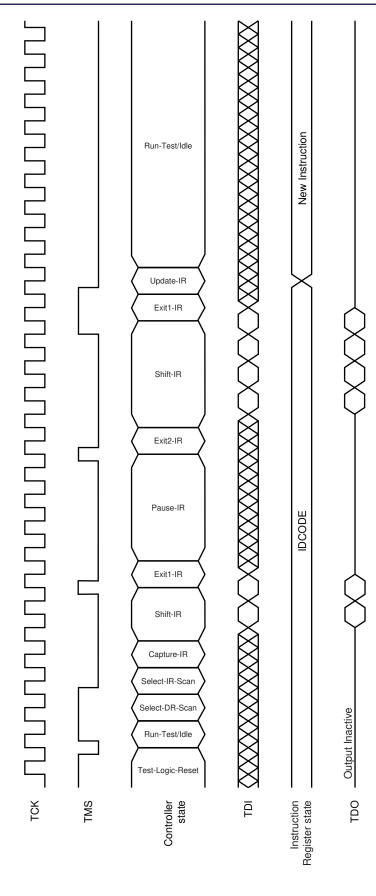


#### **TAP Controller State Diagram**

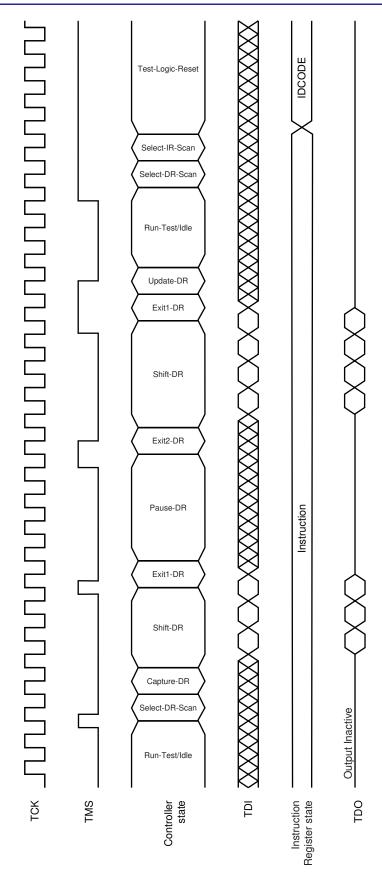


#### **Disabling the Test Access Port**

It is possible to use this device without utilizing the TAP. To disable the TAP Controller without interfering with normal operation of the device, TCK must be tied to  $V_{SS}$  to preclude mid level inputs. TDI and TMS may be left open but fix them to  $V_{DD}$  via a resistor of about 1 k $\Omega$  when the TAP controller is not used. TDO should be left unconnected also when the TAP controller is not used.



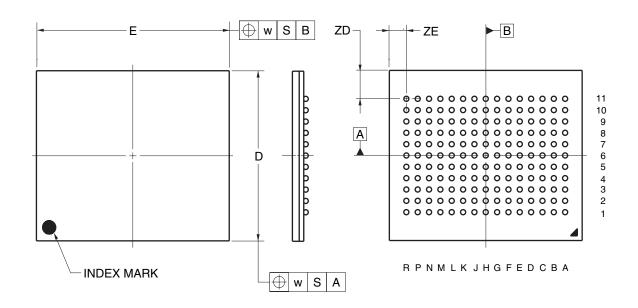
Test Logic Operation (Instruction Scan)

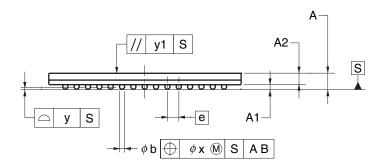


Test Logic (Data Scan)

## **Package Dimensions**

## 165-PIN PLASTIC BGA(15x17)





	(UNIT:mm)
ITEM	DIMENSIONS
D	15.00±0.10
E	17.00±0.10
W	0.30
Α	1.35±0.11
A1	0.37±0.05
A2	0.98
е	1.00
b	0.50 <sup>+0.10</sup> <sub>-0.05</sub>
Х	0.10
У	0.15
y1	0.25
ZD	2.50
ZE	1.50
	P165F5-100-FQ1-1

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## **Recommended Soldering Condition**

Please consult with our sales offices for soldering conditions of these products.

## **Types of Surface Mount Devices**

 $\mu$ PD44324185BF5-FQ1 : 165-pin PLASTIC BGA (15 x 17)  $\mu$ PD44324365BF5-FQ1 : 165-pin PLASTIC BGA (15 x 17)

## **Quality Grade**

- A quality grade of the products is "Standard".
- Anti-radioactive design is not implemented in the products.
- Semiconductor devices have the possibility of unexpected defects by affection of cosmic ray that reach to the ground and so forth.

**Revision History** 

## $\mu \mathrm{PD44324185B}$ , $\,\mu \mathrm{PD44324365B}$

Rev.	Date	Description		
nev.	Date	Page	Summary	
1st edition	'08.03.01	-	New Preliminary Data Sheet	
2nd edition	'10.03.01	P14	DC Characteristics (Modification, Spec of I <sub>DD</sub> and I <sub>SB1</sub> )	
		P15	Thermal Characteristics (Modification, Spec)	
Rev.1.00	'10.09.10	Throughout	Preliminary Data Sheet → Data Sheet	
Rev.2.00	'11.09.12	Throughout	Add Lead and the extended temperature operation product	

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